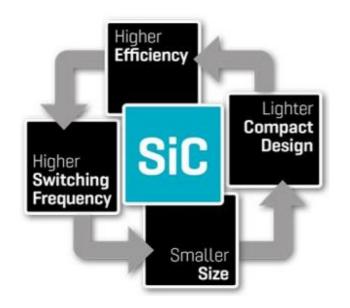
Use Cases of SiC Technology in Industrial Applications

David Chilachava, Technical Marketing Manager, Vincotech GmbH

Bodo's
Wide Bandgap
Event 2024
Making WBG Designs Happen



Use cases of SiC technology in industrial applications



Where does increased SiC content offer superior cost-performance ratio?







New regulations and standards drive heating and cooling systems to higher efficiency levels. SiC makes it easy to meet the requirements

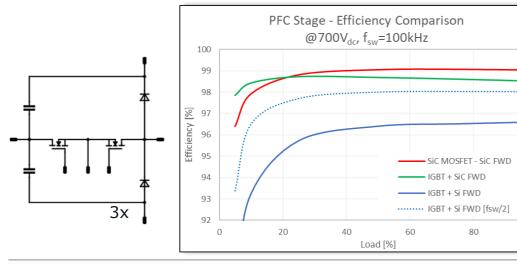
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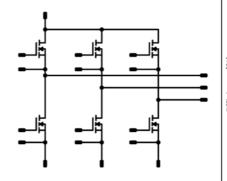
SiC in PFC converters

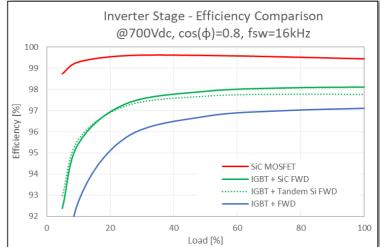
- / More compact design
- / More energy efficient
- Cost savings for system components
- / Use of SiC diodes is crucial

SiC in motor inverters

- / High efficiency across entire load profile
- / Increasing power density
- / Reducing audible noise level
 - More cost-effective solution for end users over the product lifetime











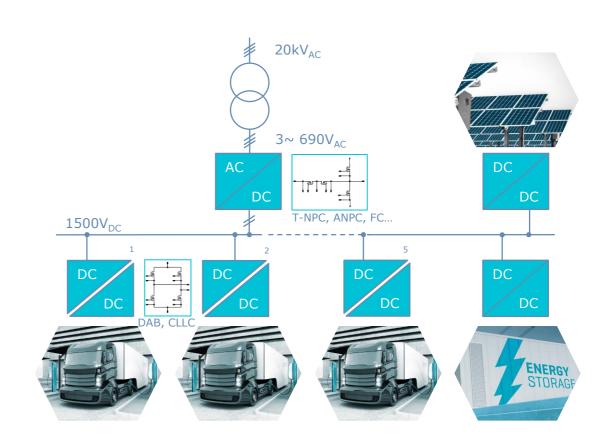
Increasing power density with SiC is the key factor towards to megawatt charging power

Today's megawatt charging systems (MCS)

- / Megawatt charging systems mainly reuse infrastructure for fast charging systems CCS
- Stacking existing 1000Vdc subunits to higher power based on 650 V & 1200 V SiC devices

NEXT generation MCS

- / DC-coupled system at 1500Vdc, simplifying integration of renewables & ESS
- / Centralized PFC stage, or SST connected directly to MV grid and modular DC/DC stage
- / More focus is needed on system reliability
- / Needs of wide range SiC components from 1.2 kV to 2.x kV SiC



Solar and ESS systems

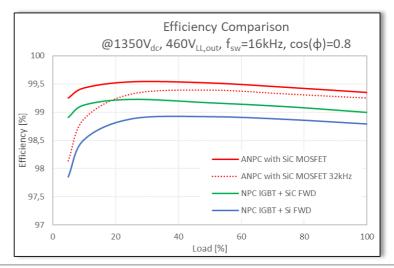


SiC is well established in commercial, utility-scale string and central PV-inverters. However, SiC content in ESS is growing faster for higher efficiency needs

PV inverter and ESS with SiC content

- Hybrid solutions (IGBTs with SiC FWD) are already popular choice in PV inverter topologies
- SiC MOSFETs offer increased power density and higher efficiency, crucial for bi-directional power conversion systems (PCS)
- / High switching frequencies and reducing inductor size and weight
- / Higher overload capability required for PCS
- For 1500V_{dc} systems ANPC inner modulation with SiC MOSFETs are popular solution offering reduced number of SiC components and achieving optimal cost-performance ratio





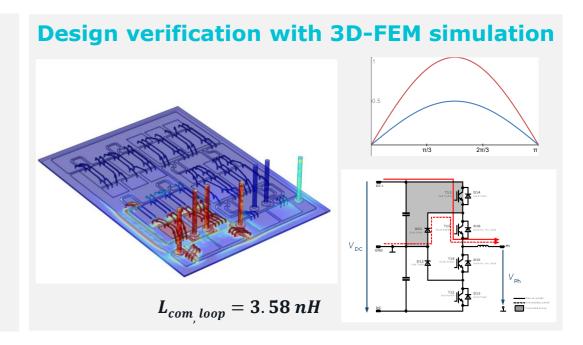
Challenges in SiC high-power module design





Switching hundreds of Amperes is only possible with chip paralleling

- / Low inductive commutation and gate loops
 - / Low overshoot
 - / Less oscillation
 - / Lower R_a can be applied \rightarrow lower switching losses
- / Symmetric commutation and gate loops
 - / Matching stray inductances
 - / Balanced current sharing and dynamic losses
- / Don't underestimate thermal design!
 - / Homogeneous R_{th} of individual MOSFETs
 - / Symmetric T_j increase \rightarrow take care of $V_{GS,th}$



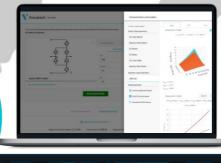
VINCOTECH offers >10 years expertise in SiC power module design!



MULTIPLE SOURCES, MORE CHOICES

- / Chip-independent power module manufacturer
- / Access to the world's leading SiC makers planar and trench technologies
- / Wide range of SiC components from 650V to 2.3kV
- Greatest freedom of choice and design flexibility tailored to customer's needs
- / Reliable supply chain

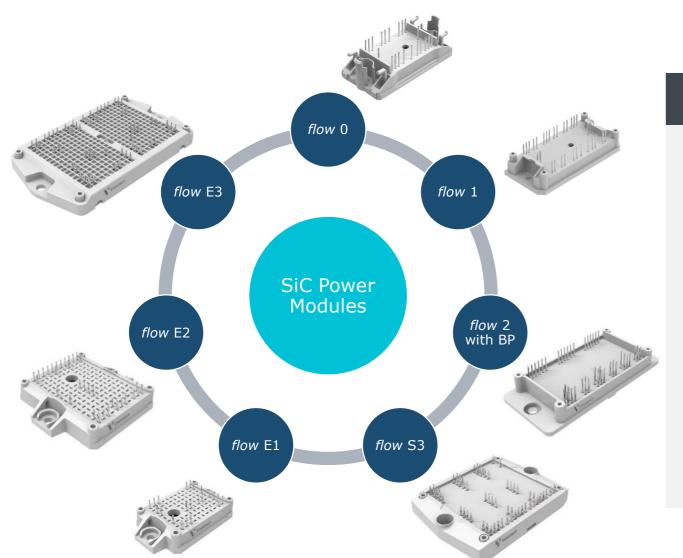
Vincotech's digital product samples based on pre-characterized switching pairs to shorter iterations and design time





Vincotech

Housing portfolio for SiC technology



KEY BENEFITS

- / Higher switching frequency in low inductive housings
- / Multi-sourced SiC-components for more freedom of choice and lower risk in the supply chain
- / Improved power cycling capability with advanced die attach technology
- / Superior thermal performance with AlN, or Si_3N_4 and homogenous R_{th} distribution
- / Integrated DC capacitors to mitigate voltage overshoot
- / Press-fit pins and pre-applied TIM to reduce production cost

EMPOWERING YOUR IDEAS

Thank you!